

SOT223 P-CHANNEL ENHANCEMENT MODE VERTICAL DMOSFET

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)}$	I_D $T_A = +25^\circ C$
-200V	25Ω @ $V_{GS} = -10V$	-200mA

Description

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

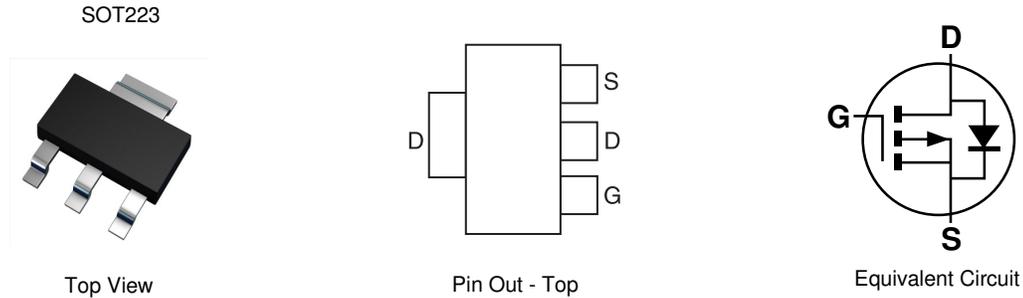
- Backlighting
- AC-DC Converters

Features and Benefits

- Low On-Resistance
- Fast Switching Speed
- Complementary Type – ZVN2120G
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208③
- Weight: 0.112 grams (Approximate)

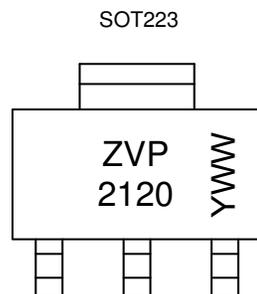


Ordering Information (Note 4)

Product	Case	Quantity per reel
ZVP2120GTA	SOT223	1,000

- Note:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



ZVP 2120 = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 5= 2015)
 WW or $\bar{W}W$ = Week Code (01~53)

Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DS}	-200	V
Continuous Drain Current	I _D	-200	mA
Pulsed Drain Current	I _{DM}	-1.2	A

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

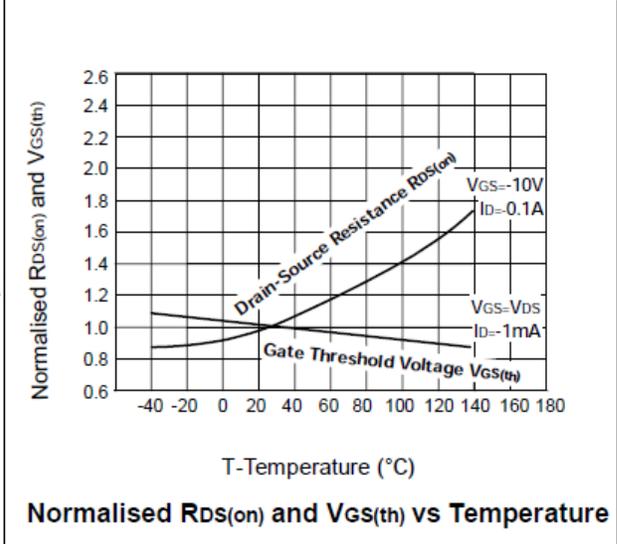
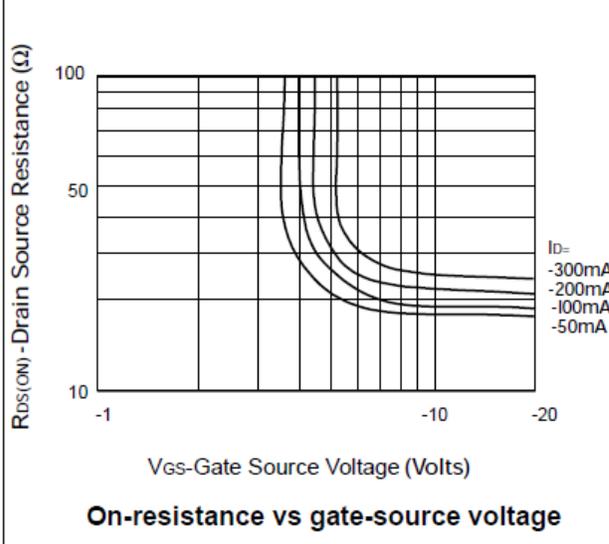
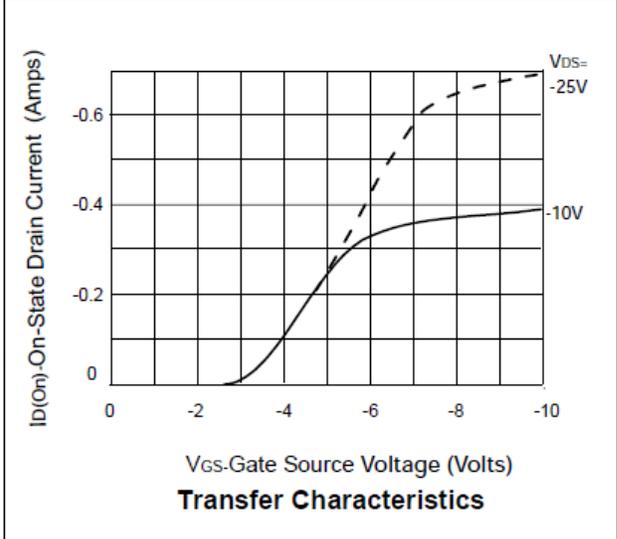
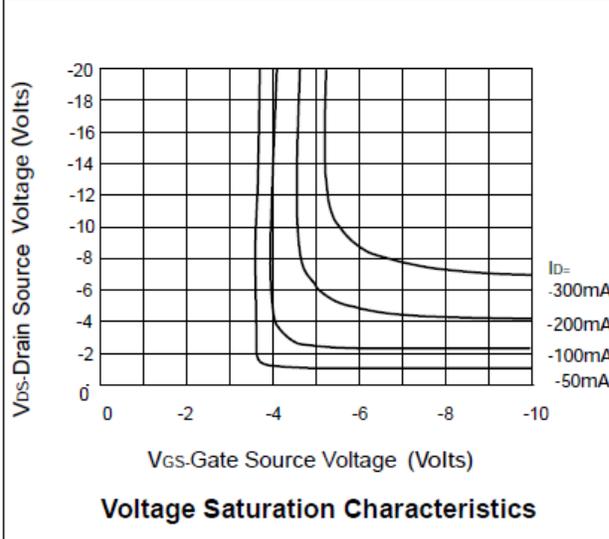
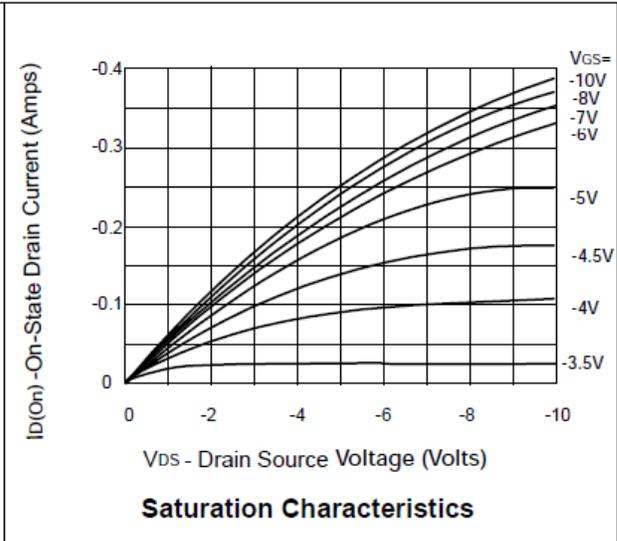
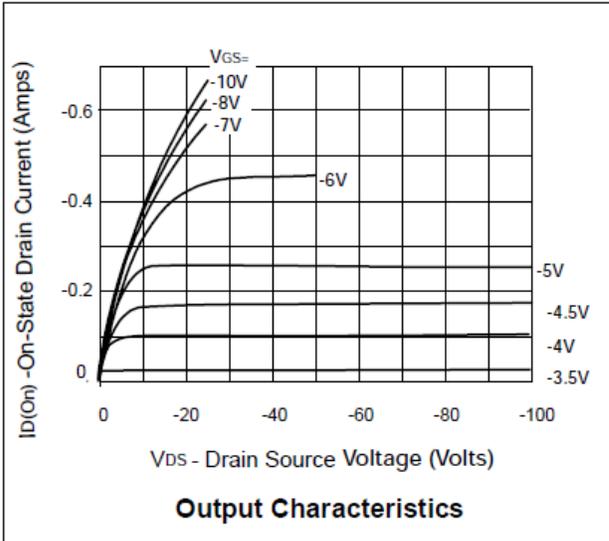
Characteristic	Symbol	Value	Units
Power Dissipation	P _{tot}	2	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

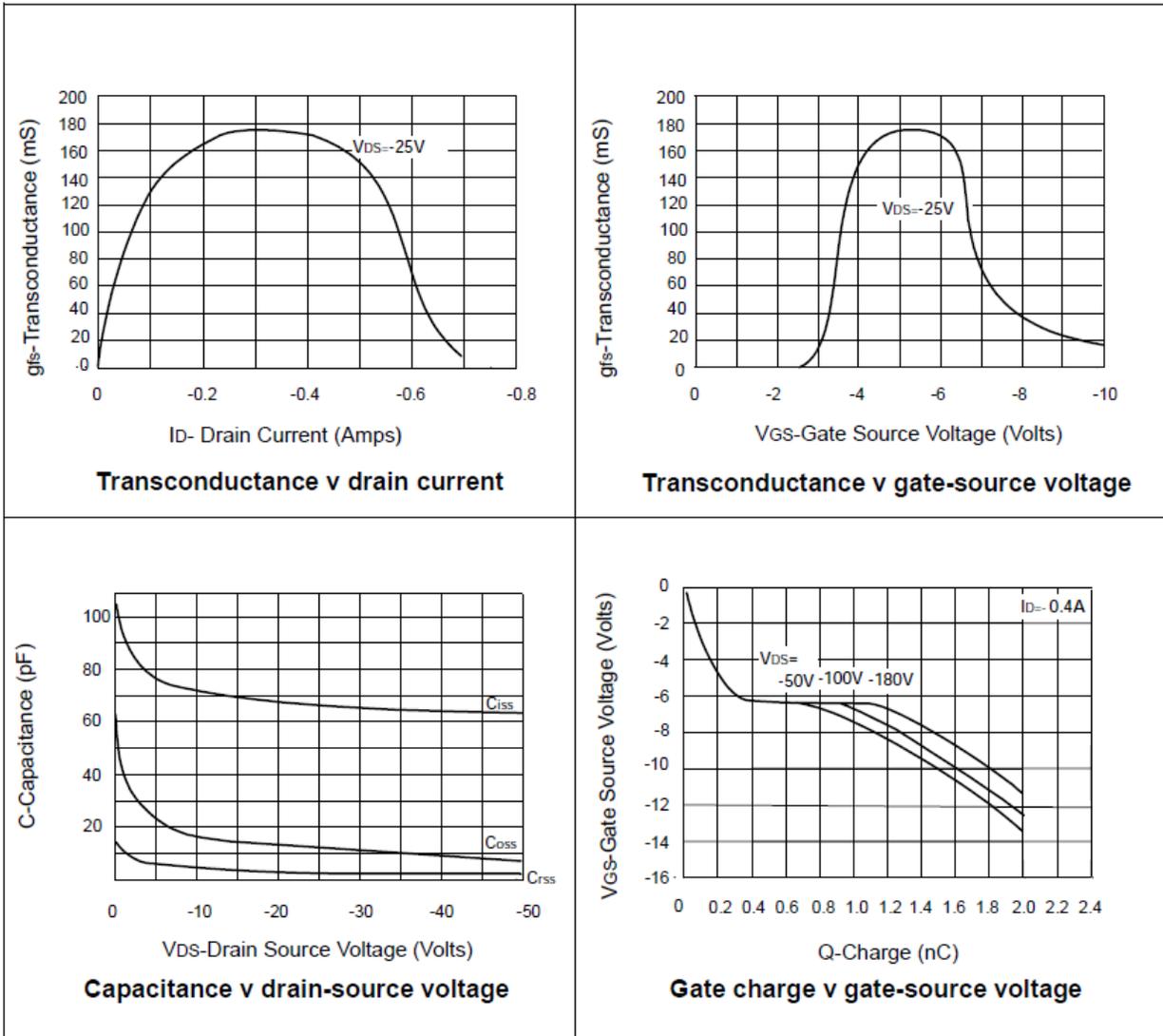
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	-200	-	-	V	I _D = -1mA, V _{GS} = 0V
Gate-Source Threshold Voltage	V _{GS(th)}	-1.5	-	-3.5	V	I _D = -1mA, V _{DS} = V _{GS}
Gate-Body Leakage	I _{GSS}	-	-	-20	nA	V _{GS} = ±20V, V _{DS} = 0V
Zero Gate Voltage Drain Current	I _{DSS}	-	-	-10	μA	V _{DS} = -200V, V _{GS} = 0V
				-100	μA	V _{DS} = -160V, V _{GS} = 0V, T = +125°C (Note 6)
On-State Drain Current (Note 5)	I _{D(on)}	-300	-	-	mA	V _{DS} = -25V, V _{GS} = -10V
Static Drain-Source On-State Resistance (Note 5)	R _{DS(on)}	-	-	25	Ω	V _{GS} = -10V, I _D = -150mA
Forward Transconductance (Notes 5 & 6)	g _{fS}	50	-	-	mS	V _{DS} = -25V, I _D = -150mA
Dynamic Characteristics (Note 6)						
Input Capacitance	C _{iss}	-	-	100	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1MHz
Common Source Output Capacitance	C _{oss}	-	-	25		
Reverse Transfer Capacitance	C _{rss}	-	-	7		
Turn-On Delay Time (Note 7)	t _{d(on)}	-	-	7	ns	V _{DD} = -25V, I _D = -150mA
Rise Time (Note 7)	t _r	-	-	15		
Turn-Off Delay Time (Note 7)	t _{d(off)}	-	-	12		
Fall Time (Note 7)	t _f	-	-	15		

- Notes: 5. Measured under pulsed conditions. Width=300μs. Duty cycle ≤ 2%.
6. Sample Test.
7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator.

Typical Characteristics

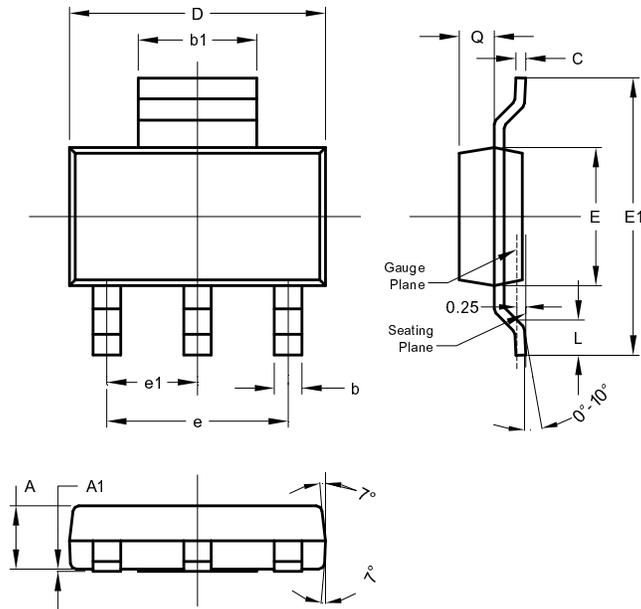


Typical Characteristics (cont.)



Package Outline Dimensions

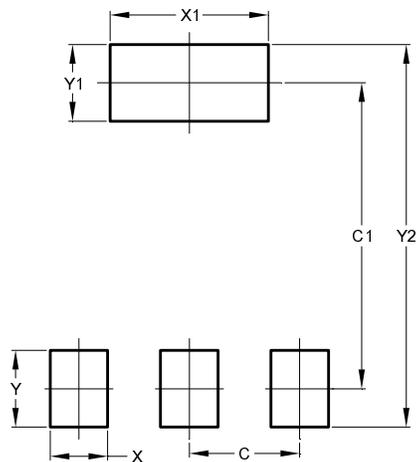
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
C2	8.00

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